

**152CMQ030-G SCHOTTKY RECTIFIER**

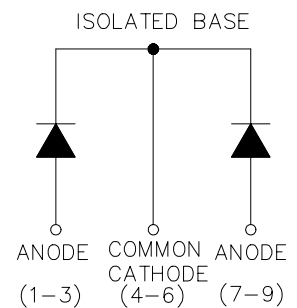
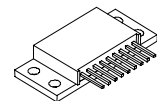
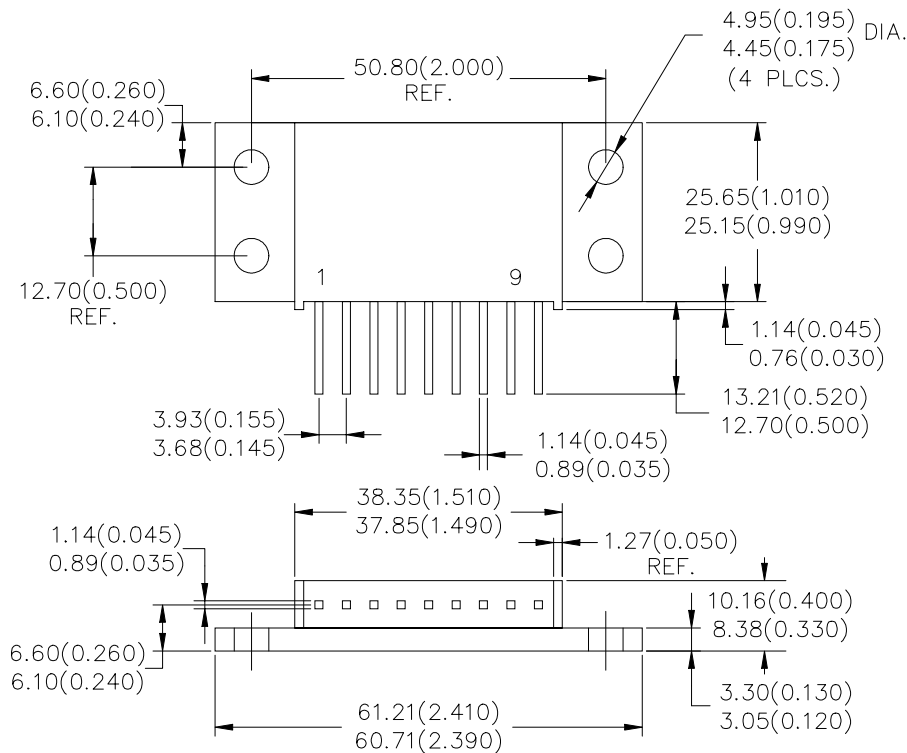
**Applications:**

- Switching power supply • Free-Wheeling diodes • Reverse battery protection • Converters

**Features:**

- 150 °C T<sub>J</sub> operation
- Isolated heatsink
- Multiple leads per terminal for high frequency, high current PC board mounting
- Low profile, high current package
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green Products in Compliance with the RoHS Directive

**Mechanical Dimensions: In Inches / mm**



**TO-249(9 pin)**

Data Sheet 3786, Rev. -  
Maximum Ratings:

*Green Products*

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	30	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_C = 85^\circ\text{C}$ , rectangular wave form	150	A
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	$I_{FSM}$	8.3 ms, half Sine pulse	1200	A
Non-Repetitive Avalanche Energy (per leg)	$E_{AS}$	$T_J = 25^\circ\text{C}$ , $I_{AS} = 15\text{ A}$ , $L = 0.6\text{ mH}$	68	mJ
Repetitive Avalanche Current (per leg)	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{sec}$ Frequency limited by $T_J$ max. $V_A = 1.5 \times V_R$ typical	15	A

**Electrical Characteristics:**

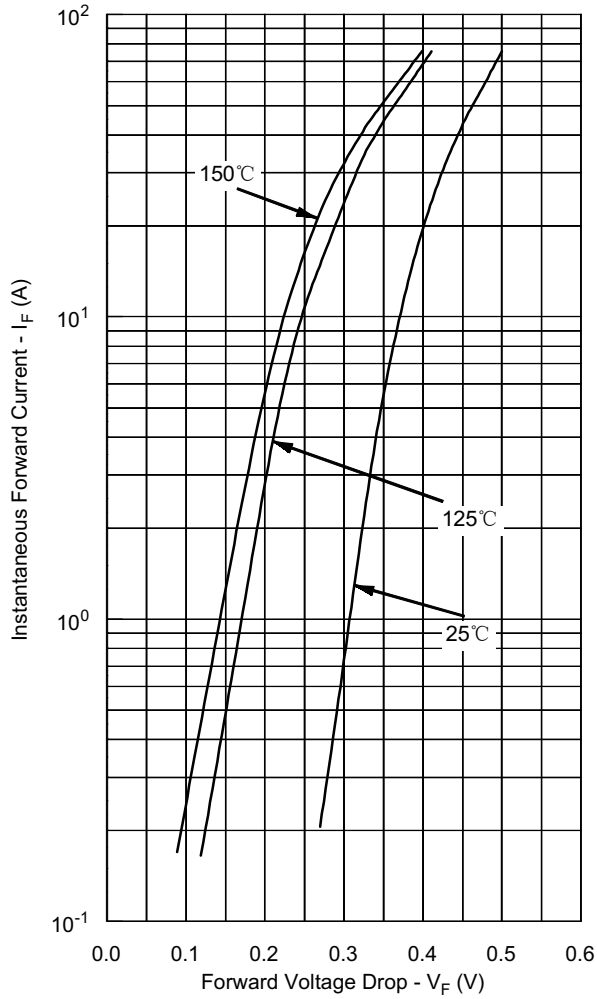
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 75 A, Pulse, $T_J = 25^\circ\text{C}$	0.55	V
		@ 150 A, Pulse, $T_J = 25^\circ\text{C}$	0.69	
	$V_{F2}$	@ 75 A, Pulse, $T_J = 125^\circ\text{C}$	0.47	V
		@ 150 A, Pulse, $T_J = 125^\circ\text{C}$	0.66	
Max. Reverse Current (per leg) *	$I_{R1}$	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	5	mA
		$I_{R2}$	@ $V_R = \text{rated } V_R$ $T_J = 125^\circ\text{C}$	
Max. Junction Capacitance (per leg)	$C_T$	@ $V_R = 5\text{ V}$ , $T_C = 25^\circ\text{C}$ $f_{SIG} = 1\text{ MHz}$	3700	pF
Typical Series Inductance (per leg)	$L_S$	Measured lead to lead 5 mm from package body	9.2	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ $\mu\text{s}$

\* Pulse Width < 300 $\mu\text{s}$ , Duty Cycle <2%

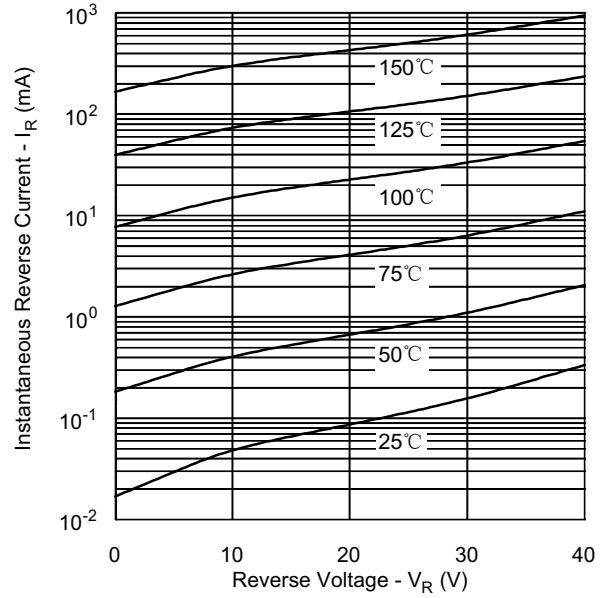
**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	$^\circ\text{C}$
Max. Storage Temperature	$T_{stg}$	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	1.0	$^\circ\text{C/W}$
Maximum Thermal Resistance Junction to Case (per device)	$R_{\theta JC}$	DC operation	0.50	$^\circ\text{C/W}$
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.10	$^\circ\text{C/W}$
Approximate Weight	wt	-	56	g
Mounting Torque	$T_M$	-	40 (min) 58 (max)	Kg-cm
Case Style	TO-249(9 pin)			

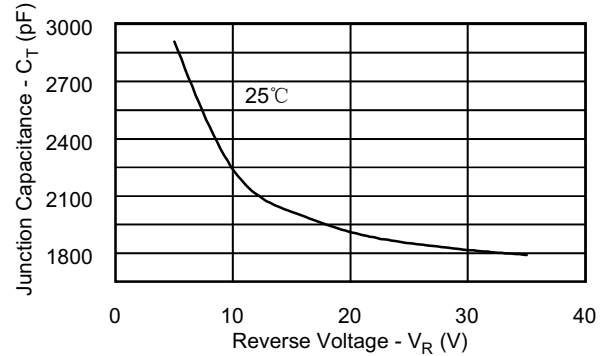
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**



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